

# 2708 8K (1K × 8) UV ERASABLE PROM

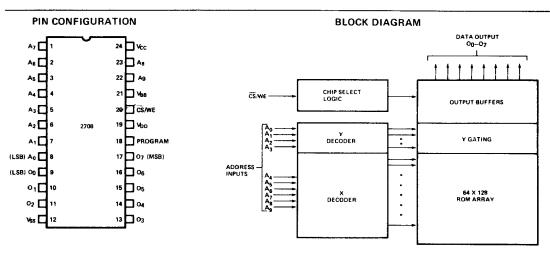
|        | Max. Power | Max. Access |
|--------|------------|-------------|
| 2708   | 800 mW     | 450 ns      |
| 2708L  | 425mW      | 450 ns      |
| 2708-1 | 800 mW     | 350 ns      |
| 2708-6 | 800 mW     | 550ns       |

- Low Power Dissipation 425 mW Max. (2708L)
- Fast Access Time 350 ns Max. (2708-1)
- Static No Clocks Required
- Data Inputs and Outputs TTL Compatible during both Read and Program Modes
- Three-State Outputs OR-Tie Capability

The Intel® 2708 is an 8192-bit ultraviolet light erasable and electrically reprogrammable EPROM, ideally suited where fast turnaround and pattern experimentation are important requirements. All data inputs and outputs are TTL compatible during both the read and program modes. The outputs are three-state, allowing direct interface with common system bus structures.

The 2708L at 425mW is available for systems requiring lower power dissipation than from the 2708. A power dissipation savings of over 50% without any sacrifice in speed is obtained with the 2708L. The 2708L has high input noise immunity and is specified at 10% power supply tolerance. A high-speed 2708-1 is also available at 350ns for microprocessors requiring fast access times.

The 2708 family is fabricated with the N-channel silicon gate FAMOS technology and is available in a 24-pin dual in-line package.



### **PIN NAMES**

| A <sub>0</sub> ·A <sub>9</sub> | ADDRESS INPUTS                 |
|--------------------------------|--------------------------------|
| 01.08                          | DATA OUTPUTS/INPUTS            |
| C\$/WE                         | CHIP SELECT/WRITE ENABLE INPUT |

### PIN CONNECTION DURING READ OR PROGRAM

|          |                            | PIN NUMBER                          |                 |               |                 |       |                 |                 |  |  |
|----------|----------------------------|-------------------------------------|-----------------|---------------|-----------------|-------|-----------------|-----------------|--|--|
| MODE     | DATA I/O<br>9-11,<br>13-17 | ADDRESS<br>INPUTS<br>1-8,<br>22, 23 | V <sub>SS</sub> | PROGRAM<br>18 | V <sub>DD</sub> | CS/WE | V <sub>BB</sub> | V <sub>CC</sub> |  |  |
| READ     | Dout                       | AIN                                 | GND             | GND           | +12             | VIL   | -5              | +5              |  |  |
| DESELECT | HIGH IMPEDANCE             | DON'T CARE                          | GND             | GND           | +12             | VIH   | -5              | +5              |  |  |
| PROGRAM  | DIN                        | AIN                                 | GND             | PULSED<br>26V | +12             | VIHW  | -5              | +5              |  |  |

### **PROGRAMMING**

The programming specifications are described in the Data Catalog PROM/ROM Programming Instructions Section.

### Absolute Maximum Ratings\*

| Absolute Maximum Ratings"                                                         |
|-----------------------------------------------------------------------------------|
| Temperature Under Bias                                                            |
| Storage Temperature                                                               |
| Vop With Respect to VRR                                                           |
| V <sub>CC</sub> and V <sub>SS</sub> With Respect to V <sub>BB</sub> +15V to -0.3V |
| All Input or Output Voltages With Respect                                         |
| to V <sub>BB</sub> During Read                                                    |
| CS/WE Input With Respect to VRR                                                   |
| During Programming +20V to -0.3V                                                  |
| Program Input With Respect to V <sub>BB</sub> +35V to -0 3V                       |
| Power Dissipation                                                                 |

### \*COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

# D.C. AND A.C. OPERATING CONDITIONS DURING READ

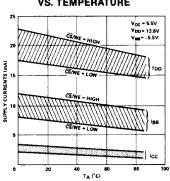
|                              | 2708     | 2708-1        | 2708-6        | 2708L     |
|------------------------------|----------|---------------|---------------|-----------|
| Temperature Range            | 0°C-70°C | 0°C-70°C      | 0°C-70°C      | 0°C-70°C  |
| V <sub>CC</sub> Power Supply | 5V ± 5%  | 5V ± 5%       | 5V ± 5%       | 5V ± 10%  |
| V <sub>DD</sub> Power Supply | 12V ± 5% | 12V ± 5%      | 12V ± 5%      | 12V ± 10% |
| V <sub>BB</sub> Power Supply | -5V ± 5% | $-5V \pm 5\%$ | $-5V \pm 5\%$ | -5V ± 10% |

## **READ OPERATION** D.C. AND OPERATING CHARACTERISTICS

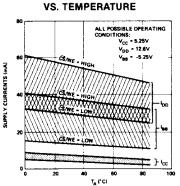
| Symbol              |                                    | 2708, 2708-1, 2708-6 Limits |          | 2708L Limits                                   |                 | Units   | Test Conditions    |      |                                           |
|---------------------|------------------------------------|-----------------------------|----------|------------------------------------------------|-----------------|---------|--------------------|------|-------------------------------------------|
|                     | Parameter                          | Min.                        | Typ.[2]  | Max.                                           | Min.            | Тур.[2] | Max.               | Omis | 100.                                      |
| l <sub>L1</sub>     | Address and Chip Select Input Sink |                             | 1        | 10                                             |                 | 1       | 10                 | μА   | $V_{1N} = 5.25V$ or $V_{1N} = V_{1L}$     |
|                     | Output Leakage Current             |                             | 1        | 10                                             |                 | 1       | 10                 | μA   | V <sub>OUT</sub> = 5.5V, CS/WE = 5V       |
| LO                  |                                    | +                           | 50       | 65                                             |                 | 21      | 28                 | mA   | Worst Case Supply Currents <sup>[4]</sup> |
| I <sub>DD</sub> [3] | V <sub>DD</sub> Supply Current     | +                           | 6        | 10                                             | <b></b>         | 2       | 4                  | mA   | All Inputs High;                          |
| I <sub>CC</sub> [3] | V <sub>CC</sub> Supply Current     |                             | 30       | 45                                             |                 | 10      | 14                 | mA   | CSWE = 5V; TA = 0°C                       |
| BB[3]               | V <sub>BB</sub> Supply Current     |                             | 30       |                                                | <del> </del>    |         |                    | V    |                                           |
| VIL                 | Input Low Voltage                  | V <sub>SS</sub>             |          | 0.65                                           | V <sub>SS</sub> |         | 0.65               |      |                                           |
| VIH                 | Input High Voltage                 | 3.0                         | <u>`</u> | V <sub>CC</sub> +1                             | 2.2             | )       | V <sub>CC</sub> +1 | V    |                                           |
| -101                |                                    | put Low Voltage 0.45 0.4 V  | v        | I <sub>OL</sub> = 1.6 mA (2708, 2708-1, 2708-6 |                 |         |                    |      |                                           |
| $V_{OL}$            | Output Low Voltage                 |                             |          | 0.45                                           |                 |         | 0.4                | ,    | I <sub>OL</sub> = 2mA (2708L)             |
|                     | Output High Voltage                | 3.7                         |          |                                                | 3.7             |         |                    | ٧    | $I_{OH} = -100 \mu A$                     |
| V <sub>OH1</sub>    |                                    | 2.4                         |          |                                                | 2.4             |         |                    | ٧    | I <sub>OH</sub> = -1mA                    |
| V <sub>OH2</sub>    | Output High Voltage                | 2.4                         |          |                                                | +               |         |                    |      |                                           |
|                     |                                    |                             |          | 800                                            | 1               |         | 325                |      | T <sub>A</sub> = 70 °C                    |
| PD Power            | Power Dissipation                  |                             |          |                                                |                 |         | 425                | mW   | T <sub>A</sub> =0°C                       |

- NOTES: 1. V<sub>BB</sub> must be applied prior to V<sub>CC</sub> and V<sub>DD</sub>. V<sub>BB</sub> must also be the last power supply switched off.
  - 2. Typical values are for  $T_A = 25\,^{\circ}\text{C}$  and nominal supply voltages.
  - 3. The total power dissipation is not calculated by summing the various currents (I<sub>DD</sub>, I<sub>CC</sub>, and I<sub>BB</sub>) multiplied by their respective voltages since current paths exist between the various power supplies and V<sub>SS</sub>. The I<sub>DD</sub>, I<sub>CC</sub>, and I<sub>BB</sub> currents should be used to determine power supply capacity only.
  - 4. IBB for the 2708L is specified in the programmed state and is 18mA maximum in the unprogrammed state.

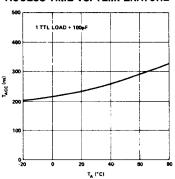
# 2708L RANGE OF SUPPLY CURRENTS VS. TEMPERATURE



# 2708, 2708-1, AND 2708-6 RANGE OF SUPPLY CURRENTS



### **ACCESS TIME VS. TEMPERATURE**



### A.C. CHARACTERISTICS

| Symbol           | Parameter                     | 2708, 2708L Limits 2708-1 Limits |      | 2708-6 |      |      |      |       |
|------------------|-------------------------------|----------------------------------|------|--------|------|------|------|-------|
|                  | Parameter                     | Min.                             | Max. | Min.   | Max. | Min. | Max. | Units |
| t <sub>ACC</sub> | Address to Output Delay       | •                                | 450  |        | 350  |      | 550  | ns    |
| tco              | Chip Select to Output Delay   |                                  | 120  |        | 120  |      | 160  | ns    |
| t <sub>DF</sub>  | Chip Deselect to Output Float | 0                                | 120  | 0      | 120  | 0    | 160  | ns    |
| t <sub>OH</sub>  | Address to Output Hold        | 0                                |      | 0      |      | 0    |      | ns    |

# CAPACITANCE [1] TA = 25°C, f = 1 MHz

| Symbol          | Parameter          | Тур. | Max. | Unit. | Conditions            |
|-----------------|--------------------|------|------|-------|-----------------------|
| C <sub>IN</sub> | Input Capacitance  | 4    | 6    | рF    | V <sub>IN</sub> = 0V  |
| Cout            | Output Capacitance | 8    | 12   | рF    | V <sub>OUT</sub> = 0V |

NOTE: 1. This parameter is periodically sampled and is not 100% tested.

### A.C. TEST CONDITIONS:

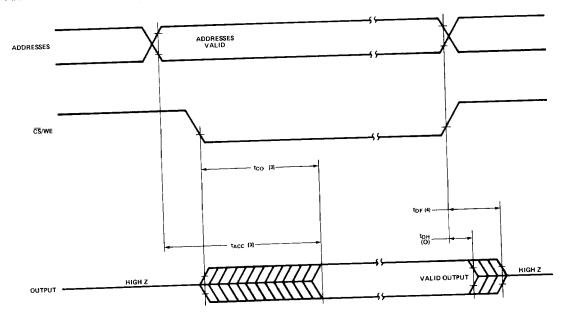
Output Load: 1 TTL gate and  $C_L = 100 \text{ pF}$ 

Input Rise and Fall Times: ≤20 ns

Timing Measurement Reference Levels: 0.8V and 2.8V for inputs; 0.8V and 2.4V for outputs.

Input Pulse Levels: 0.65V to 3.0V

# A.C. WAVEFORMS [2]



### NOTES:

- ALL TIMES SHOWN IN PARENTHESES ARE MINIMUM AND ARE NSEC UNLESS OTHERWISE SPECIFIED.
   GS MAY BE DELAYED UP TO IACC¹CO AFTER ADDRESSES ARE VALID
- WITHOUT IMPACT ON TACC:

  WITHOUT IMPACT ON TACC:

  4. TOP IS SPECIFIED FROM CS OR ADDRESS CHANGE, WHICHEVER OCCURS FIRST.

# **ERASURE CHARACTERISTICS**

The erasure characteristics of the 2708 family are such that erasure begins to occur when exposed to light with wavelengths shorter than approximately 4000 Angstroms (Å). It should be noted that sunlight and certain types of fluorescent lamps have wavelengths in the 3000-4000Å range. Data show that constant exposure to room level fluorescent lighting could erase the typical device in approximately 3 years, while it would take approximately 1 week to cause erasure when exposed to direct sunlight. If the 2708 is to be exposed to these types of lighting conditions for extended periods of time, opaque labels are available from Intel which should be placed over the 2708 window to prevent unintentional erasure.

The recommended erasure procedure (see Data Catalog PROM/ROM Programming Instructions Section) for the 2708 family is exposure to shortwave ultraviolet light which has a wavelength of 2537 Angstroms (Å). The integrated dose (i.e., UV intensity X exposure time) for erasure should be a minimum of 15 W-sec/cm<sup>2</sup>. The erasure time with this dosage is approximately 15 to 20 minutes using an ultraviolet lamp with a 12000  $\mu$ W/cm<sup>2</sup> power rating. The device should be placed within 1 inch of the lamp tubes during erasure. Some lamps have a filter on their tubes which should be removed before erasure.